

RF Low Noise FET CE3521M4

20 GHz Low Noise FET in Dual Mold Plastic PKG

DESCRIPTION

- Low Noise and High Gain
- Original Dual Mold Plastic package

FEATURES

• Low noise figure and high associated gain: NF = 0.70 dB TYP., Ga = 11.9 dB TYP. $@V_{DS} = 2 V$, I_D = 10 mA, f = 20 GHz

PACKAGE

• Flat-lead 4-pin thin-type super minimold package



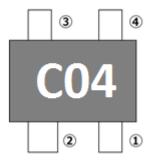
APPLICATIONS

- DBS LNB gain-stage, Mix-stage
- Low noise amplifier for microwave communication systems

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Description
CE3521M4	CE3521M4-C2	Flat-lead 4-pin	C04	 Embossed tape 8 mm wide
		thin-type super		Pin 1 (source), Pin 2 (drain)
		minimold		face the perforation side of
		package		the tape
				MOQ 15 kpcs/reel

PIN CONFIGURATION AND INTERNAL BLOCK DIAGRAM



Pin No.	Pin Name
1	Source
2	Drain
3	Source
4	Gate

ABSOLUTE MAXIMUM RATINGS

$(TA = +25^{\circ}C, unless otherwise specified)$

Parameter	Symbol	Rating	Unit
Drain to Source Voltage	V _{DS}	4.0	V
Gate to Source Voltage	V _{GS}	-3.0	V
Drain Current	Ι _D	I _{DSS}	mA
Gate Current	l _G	80	μA
Total Power Dissipation	P _{tot}	125	mW
Channel Temperature	T _{ch}	+150	°C
Storage Temperature	T _{stg}	-55 to +125	°C
Operation Temperature	T _{op}	-55 to +125 ^{Note}	°C

Note Refer to Total Power Dissipation vs. Ambient Temperature graph on page 4

RECOMMENDED OPERATING RANGE

(TA = +25°C, unless otherwise specified) Parameter Symbol MIN. TYP. MAX. Unit Drain to Source Voltage V V_{DS} +1 +2 +3 **Drain Current** 5 10 15 mΑ I_{D}

This document is subject to change without notice.

ELECTRICAL CHARACTERISTICS

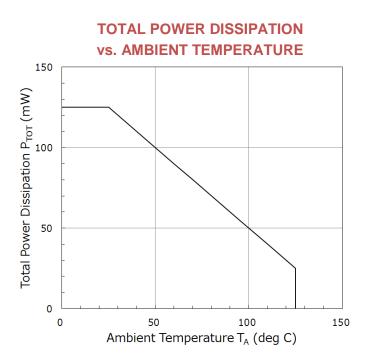
$(TA = +25^{\circ}C, unless otherwise specified)$

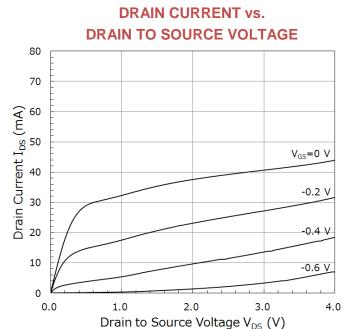
Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	I _{GSO}	V _{GS} = -3.0V	-	0.4	10	μA
Saturated Drain Current	I _{DSS}	$V_{DS} = 2V, V_{GS} = 0V$	23	40	57	mA
Gate to Source Cut-off Voltage	V _{GS(off)}	$V_{DS} = 2V, I_{D} = 100 \mu A$	-1.10	-0.75	-0.39	V
Transconductance	Gm	$V_{DS} = 2V, I_{D} = 10mA$	47	62	-	mS
Noise Figure	NF	$V_{DS} = 2V, I_{D} = 10mA,$	-	0.70	1.05	dB
Associated Gain	Ga	f = 20GHz	9.9	11.9	-	dB



TYPICAL CHARACTERISTICS :

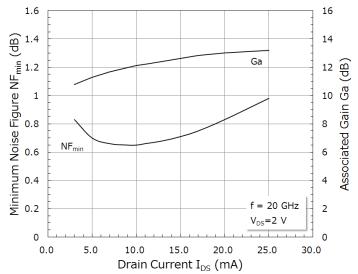
(TA=+25℃, unless otherwise specified)





DRAIN CURRENT vs. GATE TO SOURCE VOLTAGE

MINIMUM NOISE FIGURE & ASSOCIATED GAIN vs. DRAIN CURRENT





S-PARAMETERS

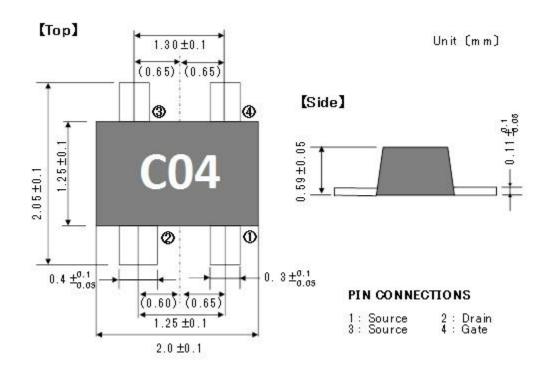
S-Parameters are available on the CEL web site.

RECOMMENDED SOLDERING CONDITIONS

Recommended Soldering Conditions are provided on the CEL web site.

PACKAGE DIMENSIONS

Flat-lead 4-pin thin-type super minimold package



REVISION HISTORY

Version	Change to current version	Page(s)
CDS-0020-03 (Issue A)	Initial datasheet	N/A
February 19, 2016		
CDS-0020-03 (Issue B)	Updated Marking Information	1, 2, 3
April 27, 2016		
CDS-0020-04 (Issue A)	Updated Specs in "Absolute Maximum Ratings" Table	2, 4, 5
July 29, 2016	Added "Typical Characteristics" section (graphs)	
-	Added "S-Parameters" and "Recommended Soldering	
	Conditions" sections	



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- Do not lick the product or in any way allow it to enter the mouth.

[CAUTION]

Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions should be used at all times.

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